



## U74AHC1G00

CMOS IC

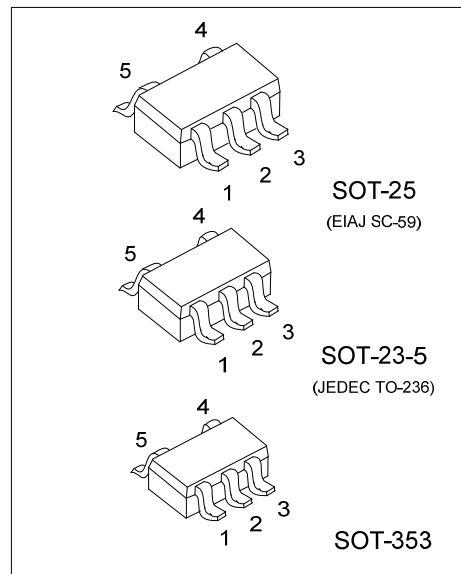
### 2-INPUT NAND GATE

#### DESCRIPTION

The **U74AHC1G00** is a 2-input NAND gate which provides the Function  $Y = \overline{A \times B}$ .

#### FEATURES

- \* Operation Voltage Range: 2~5.5V
- \* Low Power Dissipation:  $I_{CC}=1.0\mu A$  (Max)
- \* High Speed:  $t_{PD}=4.3ns$  (Typ)

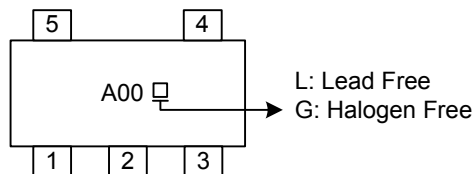


#### ORDERING INFORMATION

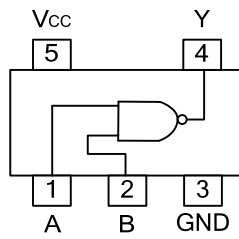
Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74AHC1G00L-AE5-R	U74AHC1G00G-AE5-R	SOT-23-5	Tape Reel
U74AHC1G00L-AF5-R	U74AHC1G00G-AF5-R	SOT-25	Tape Reel
U74AHC1G00L-AL5-R	U74AHC1G00G-AL5-R	SOT-353	Tape Reel

<p>U74AHC1G00G-AE5-R</p> <p>(1) Packing Type (2) Package Type (3) Green Package</p>	<p>(1) R: Tape Reel (2) AE5: SOT-23-5, AF5: SOT-25, AL5: SOT-353 (3) G: Halogen Free and Lead Free, L: Lead Free</p>
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#### MARKING



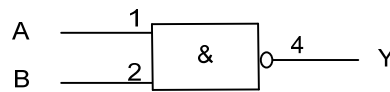
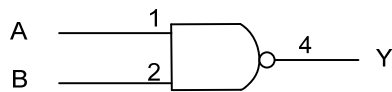
■ PIN CONFIGURATION



■ FUNCTION TABLE (each gate)

INPUT		OUTPUT
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

■ LOGIC DIAGRAM (positive logic)



## ■ ABSOLUTE MAXIMUM RATING (Note 1)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	$V_{CC}$	-0.5~7	V
Input Voltage	$V_{IN}$	-0.5~7	V
Output Voltage	$V_{OUT}$	-0.5~ $V_{CC}+0.5$	V
Input Clamp Current	$I_{IK}$	-20	mA
Output Clamp Current	$I_{OK}$	±20	mA
Output Current	$I_{OUT}$	±25	mA
$V_{CC}$ or GND Current	$I_{CC}$	±50	mA
Storage Temperature	$T_{STG}$	-65 ~ +150	°C

Notes: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.  
 2. Absolute maximum ratings are those values beyond which the device could be permanently damaged.  
 Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## ■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	$V_{CC}$		2		5.5	V
Input Voltage	$V_{IN}$		0		5.5	V
Output Voltage	$V_{OUT}$		0		$V_{CC}$	V
High-Level Output Current	$I_{OH}$	$V_{CC}=2V$			-50	μA
		$V_{CC}=3.3±0.3V$			-4	mA
		$V_{CC}=5±0.3V$			-8	mA
Low-Level Output Current	$I_{OL}$	$V_{CC}=2V$			50	μA
		$V_{CC}=3.3±0.3V$			4	mA
		$V_{CC}=5±0.5V$			8	mA
Input Rise and Fall Times	dt/dv	$V_{CC}=3.3+0.3V$			100	ns/V
		$V_{CC}=5.0+0.5V$			20	
Operating Temperature	$T_{OPR}$		-40		85	°C

## ■ STATIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	$T_A=25^{\circ}C$			$T_A=-40\sim 85^{\circ}C$		UNIT
			MIN	TYP	MAX	MIN	MAX	
High-Level Input Voltage	$V_{IH}$	$V_{CC}=2.0V$	1.5			1.5		V
		$V_{CC}=3.0V$	2.1			2.1		
		$V_{CC}=5.5V$	3.85			3.85		
Low-Level Input Voltage	$V_{IL}$	$V_{CC}=2.0V$			0.5		0.5	V
		$V_{CC}=3.0V$			0.9		0.9	
		$V_{CC}=5.5V$			1.65		1.65	
High-Level Output Voltage	$V_{OH}$	$V_{CC}=2.0V, I_{OH}=-50\mu A$	1.9	2.0		1.9		V
		$V_{CC}=3.0V, I_{OH}=-50\mu A$	2.9	3.0		2.9		
		$V_{CC}=4.5V, I_{OH}=-50\mu A$	4.4	4.5		4.4		
		$V_{CC}=3.0V, I_{OH}=-4mA$	2.58			2.48		
		$V_{CC}=4.5V, I_{OH}=-8mA$	3.94			3.8		
Low-Level Output Voltage	$V_{OL}$	$V_{CC}=2.0V, I_{OL}=50\mu A$			0.1		0.1	V
		$V_{CC}=3.0V, I_{OL}=50\mu A$			0.1		0.1	
		$V_{CC}=4.5V, I_{OL}=50\mu A$			0.1		0.1	
		$V_{CC}=3.0V, I_{OL}=4mA$			0.36		0.44	
		$V_{CC}=4.5V, I_{OL}=8mA$			0.36		0.44	
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=0\sim 5.5V, V_{IN}=V_{CC}$ or GND			±0.1		±1	μA
Quiescent Supply Current	$I_{CC}$	$V_{CC}=5.5V, V_{IN}=V_{CC}$ or GND, $I_{OUT}=0$			1		10	μA
Input Capacitance	$C_{IN}$	$V_{CC}=5V, V_{IN}=V_{CC}$ or GND		4	10		10	pF

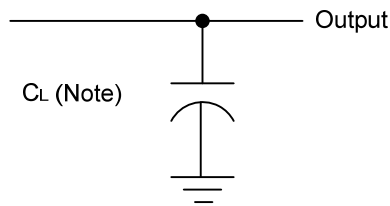
■ DYNAMIC CHARACTERISTICS (Input:  $t_R, t_F \leq 3\text{ns}$ ;  $P_{RR} \leq 1\text{MHz}$ )

PARAMETER	SYMBOL	TEST CONDITIONS	$T_A=25^\circ\text{C}$			$T_A=-40\sim 85^\circ\text{C}$		UNIT
			MIN	TYP	MAX	MIN	MAX	
Propagation Delay Time Input (A or B) to Output(Y)	$t_{PLH}$	$V_{CC}=3.3\pm 0.3, C_L=15\text{pF}$		5.5	7.9	1	9.5	ns
	$t_{PHL}$			5.5	7.9	1	9.5	
	$t_{PLH}$	$V_{CC}=3.3\pm 0.3, C_L=50\text{pF}$		8	11.4	1	13	
	$t_{PHL}$			8	11.4	1	13	
Propagation Delay Time Input (A or B) to Output(Y)	$t_{PLH}$	$V_{CC}=5\pm 0.5, C_L=15\text{pF}$		3.7	5.5	1	6.5	ns
	$t_{PHL}$			3.7	5.5	1	6.5	
	$t_{PLH}$	$V_{CC}=5\pm 0.5, C_L=50\text{pF}$		5.2	7.5	1	8.5	
	$t_{PHL}$			5.2	7.5	1	8.5	

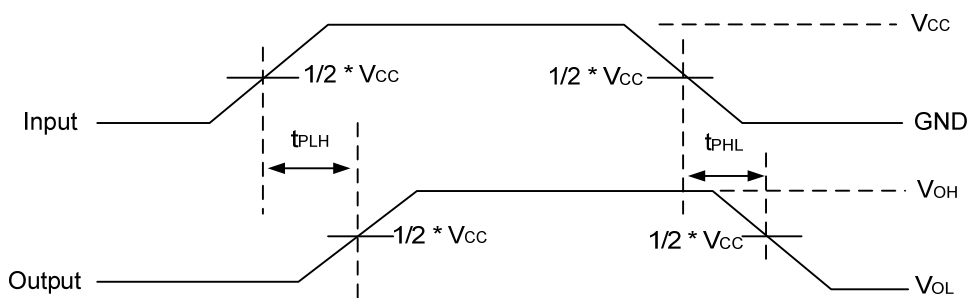
■ OPERATING CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	$C_{PD}$	No load, $f=1\text{MHz}, V_{CC}=5$		9.5		pF

■ TEST CIRCUIT AND WAVEFORMS



Note:  $C_L$  includes probe and jig capacitance.



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